

The package design of these emitters is optimized for efficient power dissipation. Copper leadframes are used to obtain better thermal performance than the traditional steel leadframes.

The wide angle emitter, HSDL-4220, is compatible with the IrDA SIR standard and can be used with the HSDL-1000 integrated SIR transceiver.

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Reference
Peak Forward Current	I_{FPK}		500	mA	[2], Fig. 2b Duty Factor = 20% Pulse Width = 100 μs
Average Forward Current	I_{FAVG}		100	mA	[2]
DC Forward Current	I_{FDC}		100	mA	[1], Fig. 2a
Power Dissipation	P_{DISS}		260	mW	
Reverse Voltage ($I_{\text{R}} = 100 \mu\text{A}$)	V_{R}	5		V	
Transient Forward Current (10 μs Pulse)	I_{FTR}		1.0	A	[3]
Operating Temperature	T_{O}	0	70	$^{\circ}\text{C}$	
Storage Temperature	T_{S}	-20	85	$^{\circ}\text{C}$	
LED Junction Temperature	T_{J}		110	$^{\circ}\text{C}$	
Lead Soldering Temperature [1.6 mm (0.063 in.) from body]			260 for 5 seconds	$^{\circ}\text{C}$	

Notes:

1. Derate linearly as shown in Figure 4.
2. Any pulsed operation cannot exceed the Absolute Max Peak Forward Current as specified in Figure 5.
3. The transient peak current is the maximum non-recurring peak current the device can withstand without damaging the LED die and the wire bonds.

Electrical Characteristics at 25 $^{\circ}\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	Reference
Forward Voltage	V_{F}	1.30	1.50 2.15	1.70	V	$I_{\text{FDC}} = 50 \text{ mA}$ $I_{\text{FPK}} = 250 \text{ mA}$	Fig. 2a Fig. 2b
Forward Voltage Temperature Coefficient	$\Delta V/\Delta T$		-2.1 -2.1		mV/ $^{\circ}\text{C}$	$I_{\text{FDC}} = 50 \text{ mA}$ $I_{\text{FDC}} = 100 \text{ mA}$	Fig. 2c
Series Resistance	R_{S}		2.8		ohms	$I_{\text{FDC}} = 100 \text{ mA}$	
Diode Capacitance	C_{O}		40		pF	0 V, 1 MHz	
Reverse Voltage	V_{R}	2	20		V	$I_{\text{R}} = 100 \mu\text{A}$	
Thermal Resistance, Junction to Pin	$R\theta_{\text{jp}}$		110		$^{\circ}\text{C}/\text{W}$		

Optical Characteristics at 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition	Reference
Radiant Optical Power HSDL-4220	P_O		19 38		mW	$I_{FDC} = 50 \text{ mA}$ $I_{FDC} = 100 \text{ mA}$	
HSDL-4230	P_O		16 32		mW	$I_{FDC} = 50 \text{ mA}$ $I_{FDC} = 100 \text{ mA}$	
Radiant On-Axis Intensity HSDL-4220	I_E	22	38 76 190	60	mW/sr	$I_{FDC} = 50 \text{ mA}$ $I_{FDC} = 100 \text{ mA}$ $I_{FPK} = 250 \text{ mA}$	Fig. 3a Fig. 3b
HSDL-4230	I_E	39	75 150 375	131	mW/sr	$I_{FDC} = 50 \text{ mA}$ $I_{FDC} = 100 \text{ mA}$ $I_{FPK} = 250 \text{ mA}$	Fig. 3a Fig. 3b
Radiant On-Axis Intensity Temperature Coefficient	$\Delta I_E / \Delta T$		-0.35 -0.35		%/°C	$I_{FDC} = 50 \text{ mA}$ $I_{FDC} = 100 \text{ mA}$	
Viewing Angle HSDL-4220	$2\theta_{1/2}$		30		deg	$I_{FDC} = 50 \text{ mA}$	Fig. 6
HSDL-4230	$2\theta_{1/2}$		17		deg	$I_{FDC} = 50 \text{ mA}$	Fig. 7
Peak Wavelength	λ_{PK}	860	875	895	nm	$I_{FDC} = 50 \text{ mA}$	Fig. 1
Peak Wavelength Temperature Coefficient	$\Delta \lambda / \Delta T$		0.25		nm/°C	$I_{FDC} = 50 \text{ mA}$	
Spectral Width—at FWHM	$\Delta \lambda$		37		nm	$I_{FDC} = 50 \text{ mA}$	Fig. 1
Optical Rise and Fall Times, 10%-90%	t_r / t_f		40		ns	$I_{FDC} = 50 \text{ mA}$	
Bandwidth	f_c		9		MHz	$I_F = 50 \text{ mA}$ $\pm 10 \text{ mA}$	Fig. 8

Ordering Information

Part Number	Lead Form	Shipping Option
HSDL-4220	Straight	Bulk
HSDL-4230	Straight	Bulk

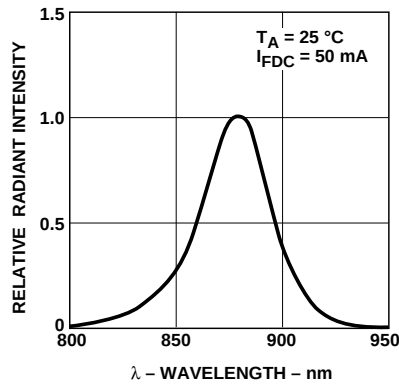


Figure 1. Relative Radiant Intensity vs. Wavelength.

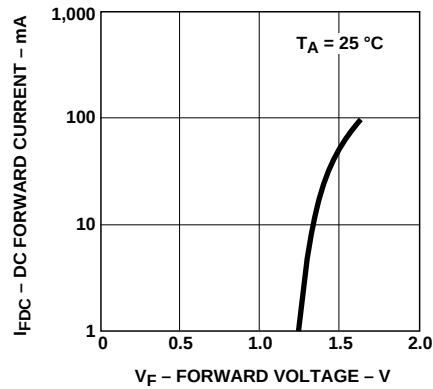


Figure 2a. DC Forward Current vs. Forward Voltage.

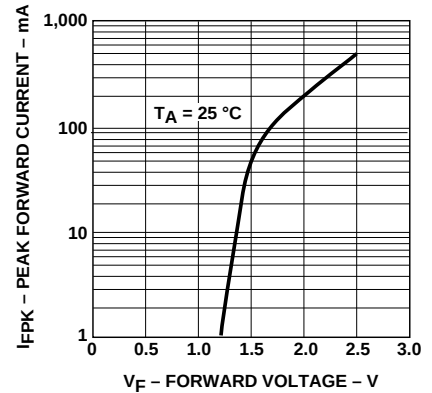


Figure 2b. Peak Forward Current vs. Forward Voltage.

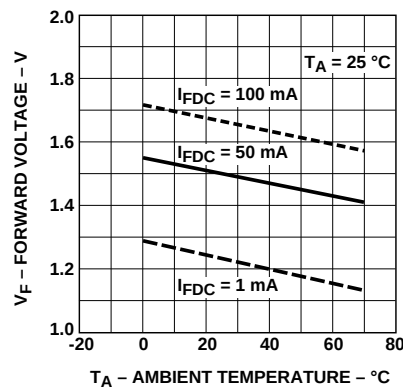


Figure 2c. Forward Voltage vs. Ambient Temperature.

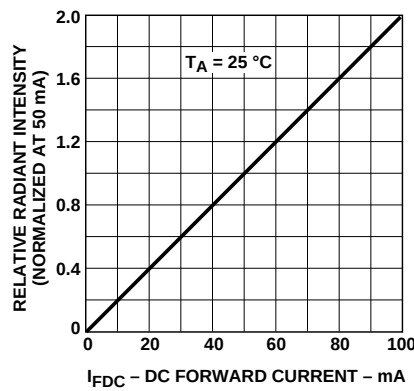


Figure 3a. Relative Radiant Intensity vs. DC Forward Current.

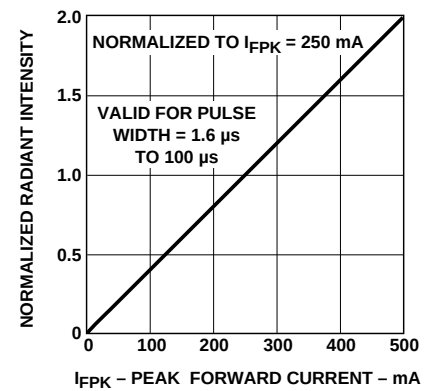


Figure 3b. Normalized Radiant Intensity vs. Peak Forward Current.

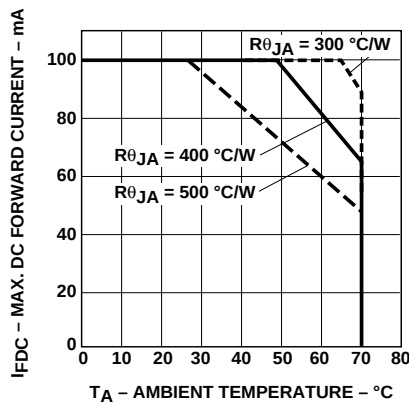


Figure 4. Maximum DC Forward Current vs. Ambient Temperature. Derated Based on $T_{JMAX} = 110^{\circ}\text{C}$.

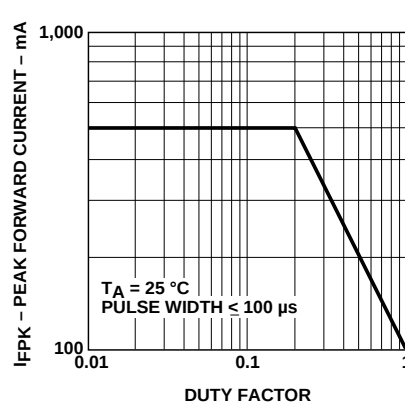


Figure 5. Maximum Peak Forward Current vs. Duty Factor.

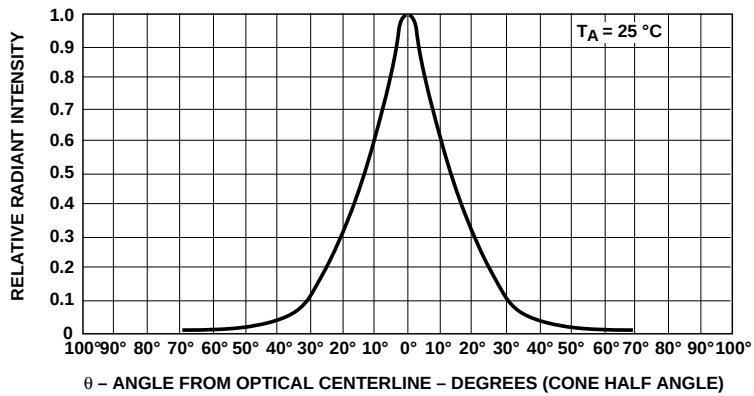


Figure 6. Relative Radiant Intensity vs. Angular Displacement HSDL-4220.

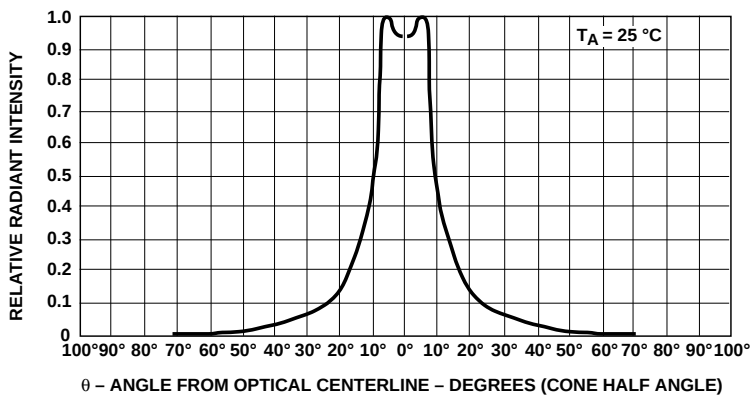


Figure 7. Relative Radiant Intensity vs. Angular Displacement HSDL-4230.

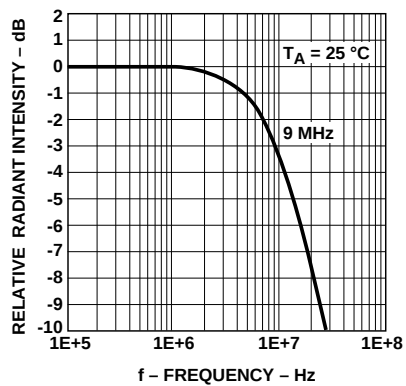
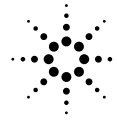


Figure 8. Relative Radiant Intensity vs. Frequency.



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Obsoletes 5968-0956E (8/98)

5968-5912E (11/99)